TOSHIBA PHOTOINTERRUPTER INFRARED LED + PHOTOTRANSISTOR

TLP831

HOME ELECTRONICS EQUIPMENT SUCH AS VCRS AND CD PLAYERS

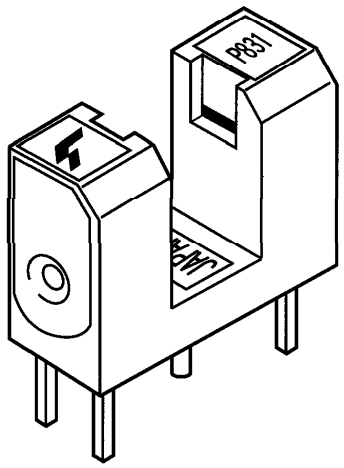
OA EQUIPMENT SUCH AS COPIERS, PRINTERS, AND FACSIMILES

AUTOMATIC SERVICING EQUIPMENT SUCH AS COMMODITY AND TICKET VENDING MACHINES

VARIOUS POSITION DETECTION SENSOR

The TLP831 photointerrupter consists of a high radiant power GaAs infrared LED and a Si phototransistor.

Housed in a short lead package, this device is ideal for automatic mounting.



JEDEC	—
EIAJ	—
TOSHIBA	11-14G1

Weight : 0.58g (Typ.)

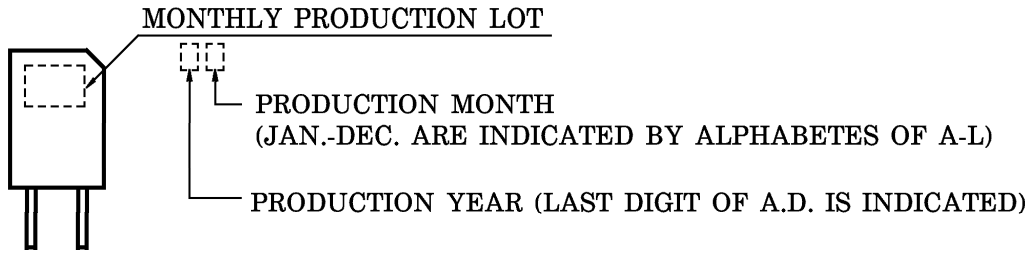
- Printed wiring board direct mounting type (with a locating pin)
- Short lead type enabling automatic mounting
  : Lead length 3.4±0.3mm
- Board thickness : 1.6mm or less
- Gap : 4.2mm
- Resolution : Slit width 0.5mm
- High current transfer ratio
  : $I_C / I_F = 5\%$ (min)
- High response speed
  : t_r, $t_f = 15\mu s$ (typ.)
- Detector side is of visible light cut type.
- Material of the package
  : Polybutylene terephthalate (UL94V-0, Black color)

MAXIMUM RATINGS (Ta = 25°C)

	CHARACTERISTIC	SYMBOL	RATING	UNIT
LED	Forward Current	I_F	50	mA
	Forward Current Derating (Ta > 25°C)	ΔI_F / °C	−0.33	mA / °C
	Reverse Voltage	V_R	5	V
DETECTER	Collector-Emitter Voltage	V_{CEO}	35	V
	Emitter-Collector Voltage	V_{ECO}	5	V
	Collector Power Dissipation	P_C	75	mW
	Collector Power Dissipation Derating (Ta > 25°C)	ΔP_C / °C	−1	mW / °C
	Collector Current	I_C	50	mA
Operating Temperature		T_{opr}	−30~85	°C
Storage Temperature		T_{stg}	−40~100	°C
Soldering Temperature (5s) (Note 1)		T_{sol}	260	°C

Note 1 : At the location of 1.5mm from the resin package bottom

PRODUCT INDICATION



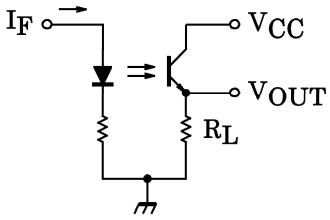
RECOMMENDED OPERATING CONDITIONS

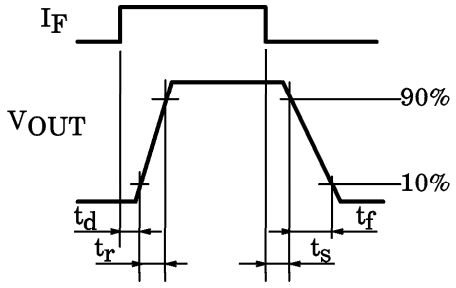
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V_{CC}	—	5	24	V
Forward Current	I_F	—	—	25	mA
Operating Temperature	T_{opr}	−10	—	75	°C

OPTO ELECTRICAL CHARACTERISTICS (Ta = 25°C)

	CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
LED	Forward Voltage	V_F	I_F = 10mA	1.00	1.15	1.30	V
	Reverse Current	I_R	V_R = 5V	—	—	10	μA
	Peak Emission Wavelength	λ_P	I_F = 10mA	—	940	—	nm
DETECTER	Dark Current	I_D (I_{CEO})	V_{CE} = 24V, I_F = 0	—	—	0.1	μA
	Peak Sensitivity Wavelength	λ_P		—	870	—	nm
COUPLED	Current Transfer Ratio	I_C / I_F	V_{CE} = 2V, I_F = 10mA	5	—	100	%
	Collector-Emitter Saturation Voltage	$V_{CE\ (sat)}$	I_F = 20mA, I_C = 0.5mA	—	0.1	0.35	V
	Rise Time	t_r	V_{CC} = 5V, I_C = 1mA	—	15	50	μs
	Fall Time	t_f	R_L = 1kΩ (Note 2)	—	15	50	

Note 2 : Switching time measurement circuit and waveform





PRECAUTIONS

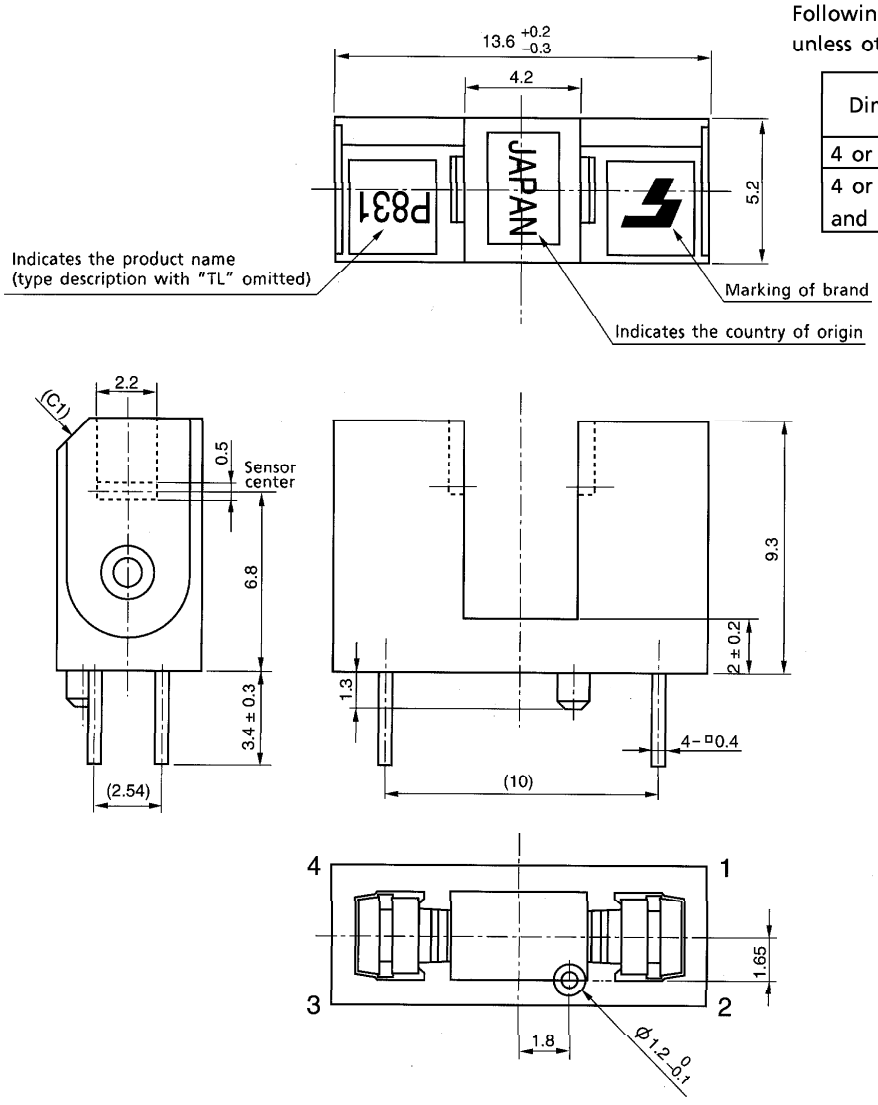
- When removing flux with chemicals after soldering, clean only the leads on the soldering side; do not dip the whole package for cleaning.
  Chemicals remaining on a surface of LED or phototransistor, if any, would have a bad influence to the optical characteristics and it may severely lower the conversion efficiency.
- The environment to install the device should be determined carefully. Oil or chemicals may cause the package to be dissolved or cracked.
- The device should be mounted on an unwarped surface.
- Install this device as avoiding the disturbance light as possible. A visible light cut-off type phototransistor which blocks light with frequencies of 700nm or above is used. However, the device cannot block infrared light with a wavelength of 700nm or more, and it may do mistaken movements.
- The current transfer ratio is gradually lowered when infrared LED is powered. The efficiency deterioration by aging should be considered when designing the circuit.

OUTLINE : TOSHIBA

Unit : mm

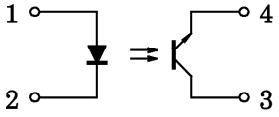
( ) : REFERENCE VALUE
Following table shows differences unless otherwise specified

Dimensions	Tolerant Differences
4 or less	± 0.1
4 or more and 18 or less	± 0.2



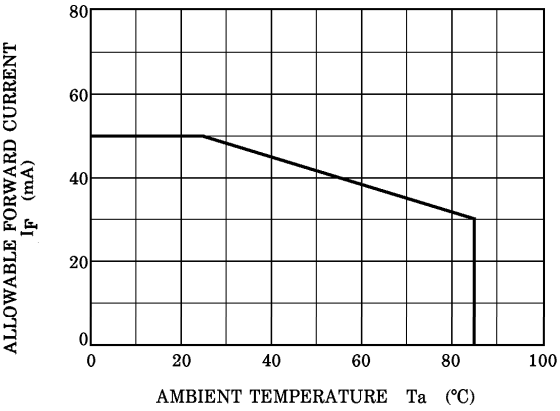
Weight : 0.58g (Typ.)

PIN CONNECTION

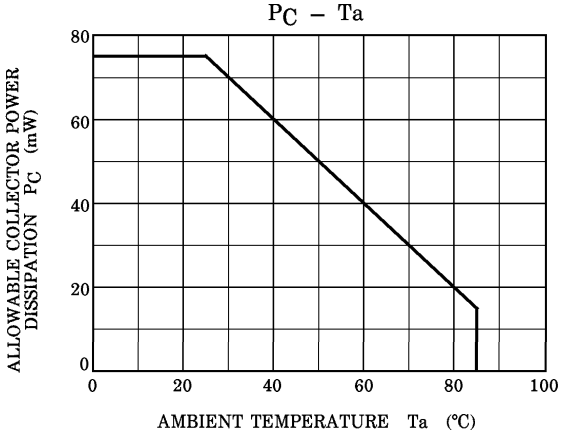


1. ANODE
2. CATHODE
3. COLLECTOR
4. EMITTER

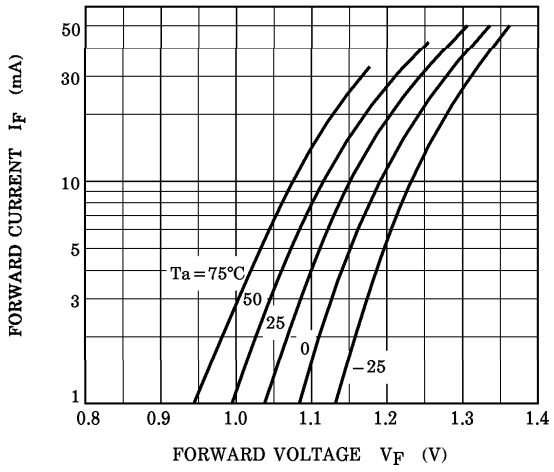
I_F – Ta



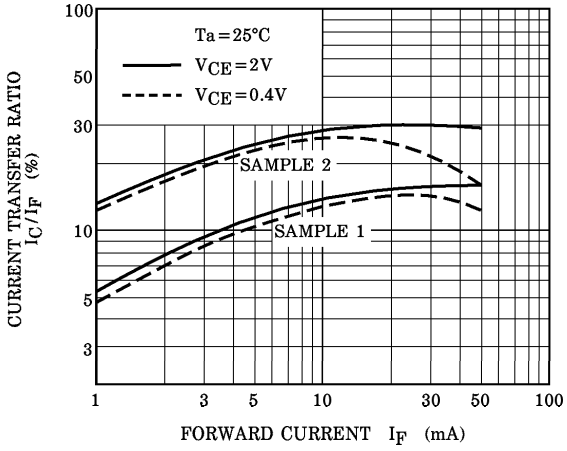
P_C – Ta



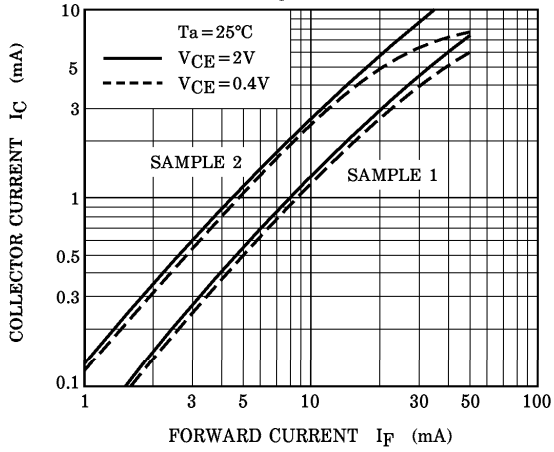
I_F – V_F (TYP.)



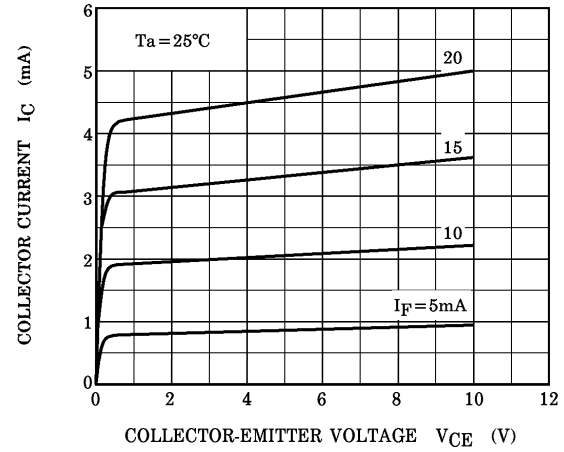
I_C / I_F – I_F



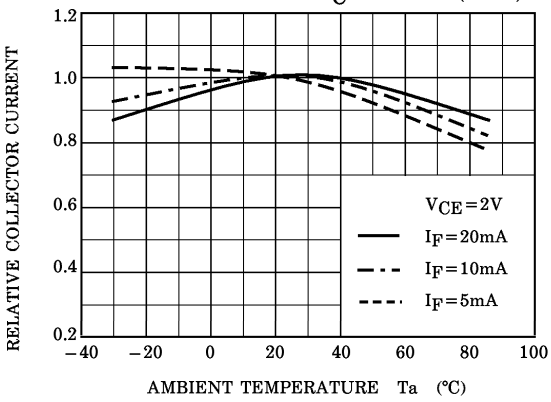
I_C – I_F



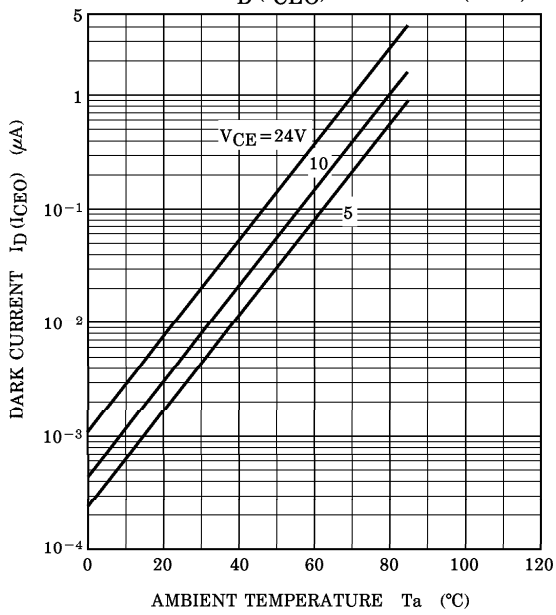
I_C – V_{CE} (TYP.)



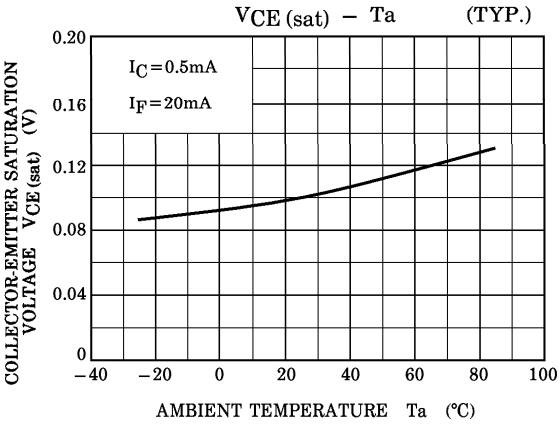
RELATIVE I_C – Ta (TYP.)



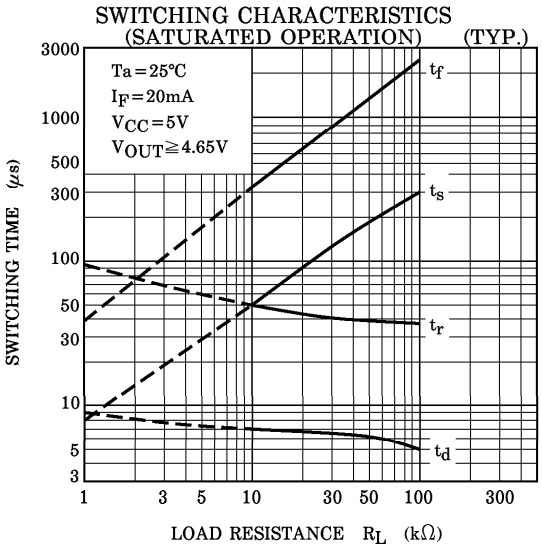
I_D (I_{CEO}) – Ta (TYP.)



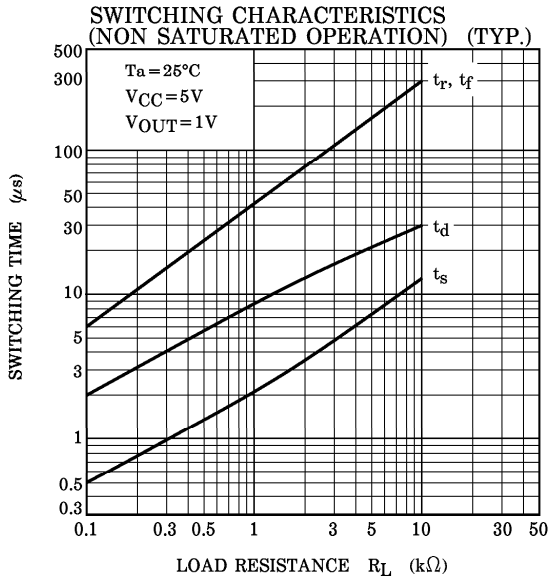
V_{CE} (sat) – Ta (TYP.)



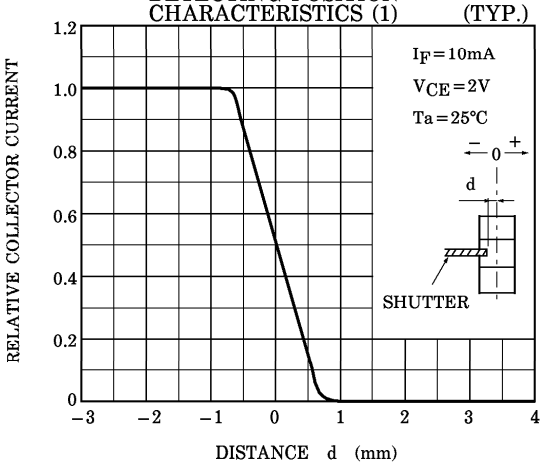
SWITCHING CHARACTERISTICS (SATURATED OPERATION) (TYP.)



SWITCHING CHARACTERISTICS (NON SATURATED OPERATION) (TYP.)



DETECTING POSITION CHARACTERISTICS (1) (TYP.)



DETECTING POSITION CHARACTERISTICS (2) (TYP.)